Diode Semiconductor Device - Page 1 of 1



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- L.	
	nclosure Material:
	Aetal
	Overall Length:
	0.250 inches
	Overall Diameter:
E	Between 0.119 inches and 0.124 inches
F	Function For Which Designed:
١	/oltage variable capacitor
N	lounting Method:
F	Press fit
F	eatures Provided:
E	Burn in and hermetically sealed case and gold plated leads
S	Semiconductor Material:
S	Silicon
٧	/oltage Rating In Volts Per Characteristic:
1	20.0 breakdown voltage, instantaneous
F	Precious Material And Location:
Т	erminal surfaces gold
F	Precious Material:
C	Gold
T	erminal Type And Quantity:
2	ferrule
S	Shelf Life:
Ν	I/a
ι	Jnit Of Measure:
-	-
C	Demilitarization:
γ	′es - demil/mli
F	iig:
1	N110a0